

S-8224A/B Series

BATTERY PROTECTION IC FOR 2-SERIAL TO 4-SERIAL CELL PACK (SECONDARY PROTECTION)

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Rev.1.4 00

The S-8224A/B Series is used for secondary protection of lithium-ion rechargeable batteries, and incorporates high-accuracy voltage detection circuits and delay circuits.

Short-circuits between cells accommodate series connection of two cells to four cells.

The S-8224B Series limits its CO pin output voltage to 11.5 V max., so a FET with the gate withstand voltage of 12 V can be used.

Features

 High-accuracy voltage detection circuit for each cell Overcharge detection voltage n (n = 1 to 4) 	
3.600 V to 4.700 V (50 mV step)	Accuracy $\pm 20 \text{ mV}$ (Ta = $\pm 25^{\circ}\text{C}$)
	Accuracy $\pm 25 \text{ mV}$ (Ta = -10°C to $+60^{\circ}\text{C}$)
Overcharge hysteresis voltage n (n = 1 to 4)*1	,
0.0 mV to -550 mV (50 mV step)	
–300 mV to –550 mV	Accuracy ±20%
–100 mV to –250 mV	Accuracy ±50 mV
–50 mV	Accuracy ±25 mV
0.0 mV	Accuracy –25 mV to +20 mV
• Delay times for overcharge detection are generated onl	y by an internal circuit (external capacitors are unnecessary)
Overcharge detection delay time is selectable:	1 s, 2 s, 4 s, 6 s, 8 s
Overcharge release delay time is selectable:	2 ms, 64 ms
 Overcharge timer reset function: 	Available, unavailable
 Output control function via CTL pin 	
 Output form is selectable (S-8224A Series): 	CMOS output, Nch open-drain output
 Output logic is selectable (S-8224A Series): 	Active "H", active "L"
CO pin output voltage is limited to 11.5 V max. (S-8224	B Series) ^{*2}
 High-withstand voltage: 	Absolute maximum rating 28 V
 Wide operation voltage range: 	3.6 V to 28 V
 Wide operation temperature range: 	Ta = –40°C to +85°C
 Low current consumption 	
During operation (V_{CU} – 1.0 V for each cell):	0.25 μA typ., 0.6 μA max. (Ta = +25°C)
During overdischarge (V _{CU} \times 0.5 V for each cell):	0.3 μA max. (Ta = +25°C)
 Lead-free (Sn 100%), halogen-free 	

*1. Select the overcharge hysteresis voltage calculated as the following formula. (Overcharge detection voltage n) + (Overcharge hysteresis voltage n) \ge 3.4 V

***2.** Only output logic active "H" is available.

Application

• Lithium-ion rechargeable battery packs (for secondary protection)

Package

• SNT-8A

Block Diagrams

1. S-8224A Series

1.1 CMOS output product

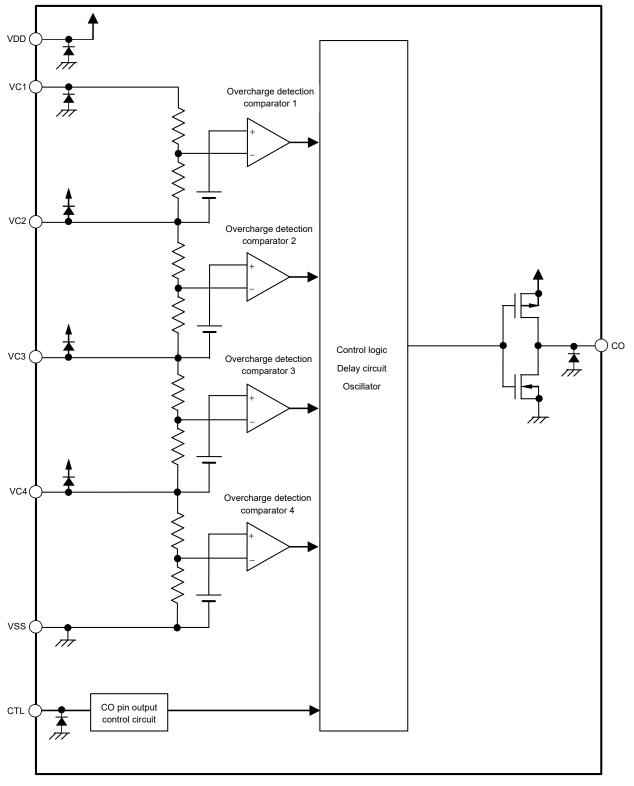


Figure 1

1.2 Nch open-drain output product

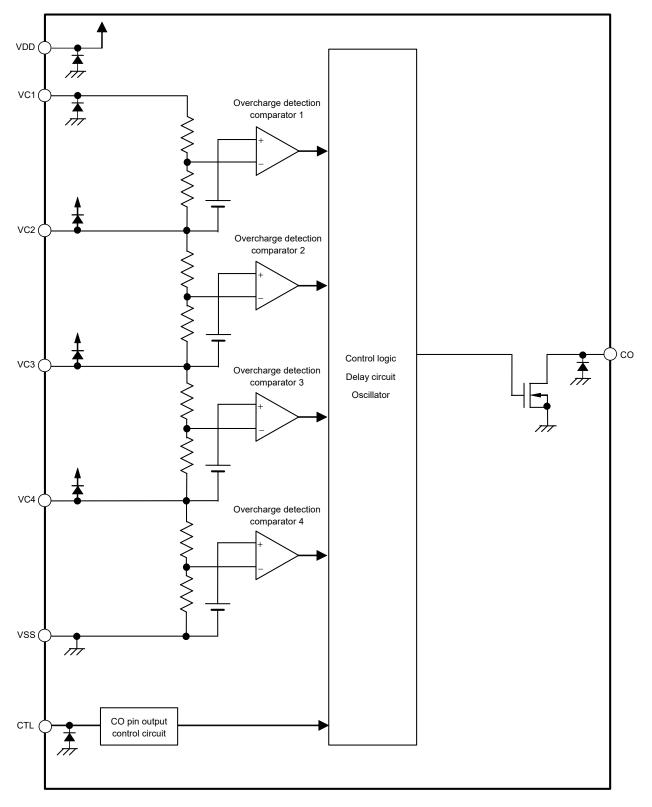
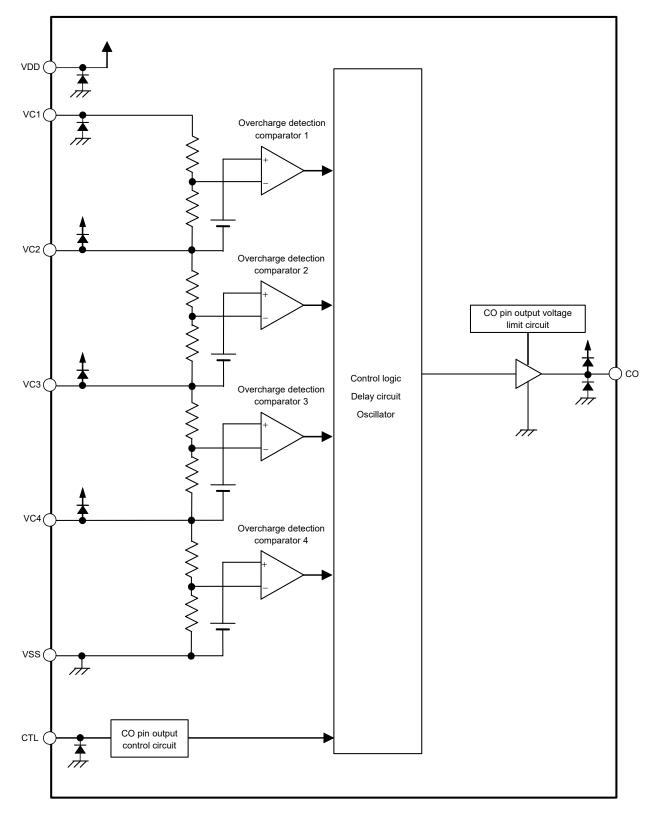


Figure 2

BATTERY PROTECTION IC FOR 2-SERIAL TO 4-SERIAL CELL PACK (SECONDARY PROTECTION) S-8224A/B Series Rev.1.4_00

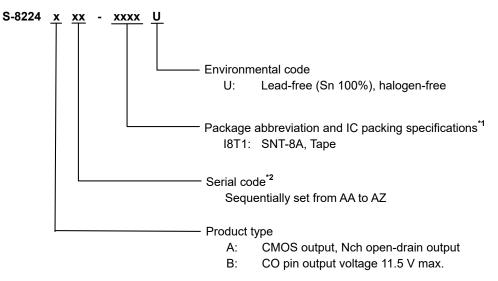
2. S-8224B Series





Product Name Structure

1. Product name



- ***1.** Refer to the tape drawing.
- *2. Refer to "3. Product name list".

2. Package

Table 1 Package Drawing Codes

Table 1 Tablage Brawnig Coase							
Package Name Dimension		Таре	Reel	Land			
SNT-8A	PH008-A-P-SD	PH008-A-C-SD	PH008-A-R-SD	PH008-A-L-SD			

3. Product name list

3.1 S-8224A Series

Table 2							
Product Name	Overcharge Detection Voltage [V _{Cu}]	Overcharge Hysteresis Voltage [V _{Hc}]	Overcharge Detection Delay Time ^{*1} [t _{cu}]	Overcharge Release Delay Time ^{*2} [t _{CL}]	Output Form ^{*3}	Output Logic ^{*4}	Overcharge timer reset function* ⁵
S-8224AAS-I8T1U	4.450 V	–400 mV	4 s	64 ms	CMOS output	Active "H"	Available
S-8224AAT-I8T1U	4.350 V	–400 mV	4 s	64 ms	CMOS output	Active "H"	Available
S-8224AAU-I8T1U	4.500 V	–400 mV	4 s	64 ms	CMOS output	Active "H"	Available
S-8224AAV-I8T1U	4.550 V	–400 mV	6 s	64 ms	CMOS output	Active "H"	Available
S-8224AAW-I8T1U	4.450 V	–400 mV	6 s	64 ms	CMOS output	Active "H"	Available
S-8224AAX-I8T1U	4.350 V	–400 mV	6 s	64 ms	CMOS output	Active "H"	Available
S-8224ABA-I8T1U	4.400 V	–400 mV	6 s	64 ms	CMOS output	Active "H"	Available
S-8224ABB-I8T1U	4.500 V	–400 mV	6 s	64 ms	CMOS output	Active "H"	Available
S-8224ABC-I8T1U	4.600 V	–400 mV	4 s	64 ms	CMOS output	Active "H"	Available
S-8224ABD-I8T1U	4.300 V	–400 mV	2 s	64 ms	CMOS output	Active "H"	Available
S-8224ABE-I8T1U	4.650 V	–400 mV	6 s	64 ms	CMOS output	Active "H"	Unavailable
S-8224ABF-I8T1U	4.700 V	–400 mV	6 s	64 ms	CMOS output	Active "H"	Unavailable

*1. Overcharge detection delay time 1 s / 2 s / 4 s / 6 s / 8 s is selectable.

***2.** Overcharge release delay time 2 ms / 64 ms is selectable.

***3.** Output form CMOS output / Nch open-drain output is selectable.

***4.** Output logic active "H" / active "L" is selectable.

***5.** Overcharge timer reset function Available / Unavailable is selectable.

Remark Please contact our sales representatives for the products with detection voltage value other than those specified above.

3. 2 S-8224B Series

	Table 3							
Dreduct Norse	Overcharge Detection	Overcharge Hysteresis	Overcharge Detection	Overcharge Release	Output	Overcharge		
Product Name	Voltage [Vcu]	Voltage [V _{нс}]	Delay Time ^{*1} [t _{c∪}]	Delay Time ^{*2} [t _{CL}]	Logic* ³	timer reset function ^{*4}		
S-8224BAA-I8T1U	4.350 V	–400 mV	4 s	2 ms	Active "H"	Available		
S-8224BAB-I8T1U	4.450 V	–400 mV	6 s	64 ms	Active "H"	Available		
S-8224BAC-I8T1U	4.350 V	–400 mV	4 s	64 ms	Active "H"	Available		

*1. Overcharge detection delay time 1 s / 2 s / 4 s / 6 s / 8 s is selectable.

***2.** Overcharge release delay time 2 ms / 64 ms is selectable.

***3.** Only output logic active "H" is available.

***4.** Overcharge timer reset function Available / Unavailable is selectable.

Remark Please contact our sales representatives for the products with detection voltage value other than those specified above.

Pin Configuration

1. SNT-8A



Figure 4

	Table 4				
Pin No.	Symbol	Description			
1	VDD	Positive power supply input pin			
2	VC1	Positive voltage connection pin of battery 1			
3	VC2	Negative voltage connection pin of battery 1 Positive voltage connection pin of battery 2			
4	VC3	Negative voltage connection pin of battery 2 Positive voltage connection pin of battery 3			
5	VC4	Negative voltage connection pin of battery 3 Positive voltage connection pin of battery 4			
6	VSS	Negative power supply input pin Negative voltage connection pin of battery 4			
7	CTL	CO pin output control pin			
8	CO	FET gate connection pin for charge control			

Absolute Maximum Ratings

		Tabl	e 5			
				(Ta =	+25°C unless otherwise spe	ecified)
	ltem		Symbol	Applied Pin	Absolute Maximum Rating	Unit
Input voltage bet	ween VDD pin and VS	SS pin	V _{DS}	VDD	V_{SS} – 0.3 to V_{SS} + 28	V
				VC1	$V_{\text{SS}} - 0.3$ to $V_{\text{SS}} + 28$	V
Input pin voltage		VIN	VC2, VC3, VC4	$V_{\text{DD}}-28$ to $V_{\text{DD}}+0.3$	V	
				CTL	$V_{\text{SS}} - 0.3$ to $V_{\text{DD}} + 0.3$	V
CO nin output	S-8224A Series	CMOS output			$V_{\text{SS}} - 0.3$ to $V_{\text{DD}} + 0.3$	V
CO pin output voltage S-8224A Series Nch open-drain output S-8224B Series		Nch open-drain output	Vco	V _{co} CO	V_{SS} – 0.3 to V_{SS} + 28	V
				$V_{\text{SS}} - 0.3$ to $V_{\text{DD}} + 0.3$	V	
Operation ambie	Operation ambient temperature		T _{opr}	_	-40 to +85	°C
Storage tempera	ture		T _{stg}	_	-40 to +125	°C

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

Thermal Resistance Value

Тур.	Max.	Unit
		Unit
211	-	°C/W
173	_	°C/W
_	-	°C/W
_	_	°C/W
_	-	°C/W

Table O

*1. Test environment: compliance with JEDEC STANDARD JESD51-2A

Remark Refer to "**■ Power Dissipation**" and **"Test Board**" for details.

Electrical Characteristics

		Table 7	(Ta = -	⊦25°C u	nless other	wise s	pecified)
Item	Symbol	Condition	Min.	Тур.	Max.	Unit	Test Circuit
Detection voltage				-			÷
Overcharge detection voltage n		Ta = +25°C	V _{CU} - 0.020	Vcu	V _{CU} + 0.020	v	1
(n = 1, 2, 3, 4)	V _{CUn}	Ta = −10°C to +60°C*1	V _{CU} - 0.025	Vcu	V _{CU} + 0.025	v	1
		$-550~mV \leq ~V_{HC} \leq -300~mV$	$V_{HC} \times 1.2$	V _{HC}	$V_{HC} \times 0.8$	V	1
		$-250 \text{ mV} \le \text{V}_{\text{HC}} \le -100 \text{ mV}$	V _{HC} – 0.050	V _{HC}	V _{HC} + 0.050	V	1
Overcharge hysteresis voltage n (n = 1, 2, 3, 4)	V _{HCn}	V_{HC} = -50 mV	V _{HC} - 0.025	V _{HC}	V _{HC} + 0.025	v	1
		V _{HC} = 0.0 mV	V _{HC} - 0.025	Vнс	V _{HC} + 0.020	V	1
Input voltage	,				i	i	i
Operation voltage between VDD pin and VSS pin	VDSOP	-	3.6	-	28	V	-
CTL pin input voltage "H"	VCTLH	-	$V_{\text{DD}} \times 0.95$	_	-	V	2
CTL pin input voltage "L"	VCTLL	_	_	-	$V_{DD}\!\times\!0.4$	V	2
Output voltage							
CO pin output voltage "H"	V _{COH}	S-8224B Series	5.0	8.0	11.5	V	2
Input Current							
Current consumption during operation	I _{OPE}	V1 = V2 = V3 = V4 = V _{CU} - 1.0 V	_	0.25	0.6	μA	3
Current consumption during overdischarge	I _{OPED}	V1 = V2 = V3 = V4 = V _{CU} × 0.5 V	_	-	0.3	μA	3
VC1 pin input current	I _{VC1}	V1 = V2 = V3 = V4 = V _{CU} - 1.0 V	-	-	0.3	μA	4
VCn pin input current (n = 2, 3, 4)	I _{VCn}	V1 = V2 = V3 = V4 = V _{CU} - 1.0 V	-0.3	0	0.3	μA	4
CTL pin input current "H"	ICTLH	-	0.6	1.3	2.0	μA	4
CTL pin input current "L"	ICTLL	-	-0.15	-	_	μA	4
Output Current	1				1		1
CO pin source current	I _{СОН}	S-8224A Series (CMOS output product), S-8224B Series	-	_	-20	μA	5
CO pin sink current	ICOL	_	20		_	μA	5
CO pin leakage current	I _{COLL}	S-8224A Series (Nch open-drain output product)	-	I	0.1	μA	5
Delay Time		· · · · · · · · · · · · · · · · · · ·					
Overcharge detection delay time	tcu	-	$t_{CU} imes 0.8$	tcu	$t_{CU} \times 1.2$	s	1
Overcharge release delay time	t _{CL}	$t_{CL} = 2 ms$ $t_{CL} = 64 ms$	1.6 51.2	2.0 64	3.0 76.8	ms ms	1 1
Overcharge timer reset delay time	t _{TR}	With overcharge timer reset function	6	12	20	ms	1
CTL pin response delay time Transition time to test mode	t _{сть} t _{тsт}		-	_	2.5 10	ms ms	2
	151		-	-	10	1115	

*1. Since products are not screened at high and low temperature, the specification for this temperature range is guaranteed by design, not tested in production.

Test Circuits

1. Overcharge detection voltage, overcharge hysteresis voltage (Test circuit 1)

Set SW1 to OFF in CMOS output product of the S-8224A Series and in the S-8224B Series, and set SW1 to ON in Nch open-drain output product of the S-8224A Series.

1. 1 Overcharge detection voltage n (Vcun)

Set V0 = 0 V, V1 = V2 = V3 = V4 = V_{CU} - 0.05 V in test circuit 1. The overcharge detection voltage 1 (V_{CU1}) is the V1 voltage when the CO pin output inverts after the voltage of V1 has been gradually increased. Overcharge detection voltage (V_{CUn}) (n = 2 to 4) can be determined in the same way as when n = 1.

1. 2 Overcharge hysteresis voltage n (VHCn)

Set V0 = 0 V, V1 = V_{CU} + 0.05 V, V2 = V3 = V4 = 2.5 V. The overcharge hysteresis voltage 1 (V_{HC1}) is the difference between V1 voltage and V_{CU1} when the CO pin output inverts again after the V1 voltage has been gradually decreased.

Overcharge hysteresis voltage (V_{HCn}) (n = 2 to 4) can be determined in the same way as when n = 1.

2. CTL pin input voltage (Test circuit 2)

Set SW1 to OFF in CMOS output product of the S-8224A Series and in the S-8224B Series, and set SW1 to ON in Nch open-drain output product of the S-8224A Series.

2. 1 CTL pin input voltage "H" (VCTLH)

Set V1 = V2 = V3 = V4 = 3.5 V, V5 = 0 V. The CTL pin input voltage "H" (V_{CTLH}) is the V5 voltage when the CO pin output inverts after the voltage of V5 has been gradually increased.

2. 2 CTL pin input voltage "L" (VCTLL)

Set V5 =14 V. The CTL pin input voltage "L" (V_{CTLL}) is the V5 voltage when the CO pin output inverts after the voltage of V5 has been gradually decreased.

3. Output voltage (S-8224B Series) (Test circuit 2)

3.1 CO pin output voltage "H"

The CO pin output voltage "H" (V_{COH}) is the voltage between the CO pin and the VSS pin when V1 = V2 = V3 = V4 = 3.5 V, V5 = 0 V.

4. Input current (Test circuit 4)

4. 1 CTL pin input current "H" (ICTLH)

Set SW2 and SW3 to ON and OFF, respectively. The CTL pin input current "H" (I_{CTLH}) is the current that flows through the CTL pin when V1 = V2 = V3 = V4 = 3.5 V.

4. 2 CTL pin input current "L" (ICTLL)

Set SW2 and SW3 to OFF and ON, respectively. The CTL pin input current "L" (I_{CTLL}) is the current that flows through the CTL pin when V1 = V2 = V3 = V4 = 3.5 V.

5. Output current (Test circuit 5)

5. 1 CMOS output product in S-8224A Series

Set SW4 and SW5 to OFF.

5. 1. 1 Active "H"

(1) CO pin source current (Ісон)

Set SW4 to ON after setting V1 to V4 = 3.5 V, V5 = 0 V, V6 = 0.5 V. I1 is the CO pin source current (I_{COH}) at that time.

(2) CO pin sink current (ICOL)

Set SW5 to ON after setting V1 to V4 = 3.5 V, V5 = 14 V, V7 = 0.5 V. I2 is the CO pin sink current (I_{COL}) at that time.

5. 1. 2 Active "L"

(1) CO pin source current (Ісон)

Set SW4 to ON after setting V1 to V4 = 3.5 V, V5 = 14 V, V6 = 0.5 V. I1 is the CO pin source current (I_{COH}) at that time.

(2) CO pin sink current (IcoL)

Set SW5 to ON after setting V1 to V4 = 3.5 V, V5 = 0 V, V7 = 0.5 V. I2 is the CO pin sink current (I_{COL}) at that time.

5. 2 Nch open-drain output product in S-8224A Series

Set SW4 and SW5 to OFF.

5. 2. 1 Active "H"

(1) CO pin leakage current (Icoll)

Set SW5 to ON after setting V1 to V4 = 7 V, V5 = 0 V, V7 = 28 V. I2 is the CO pin leakage current (I_{COLL}) at that time.

(2) CO pin sink current (I_{COL})

Set SW5 to ON after setting V1 to V4 = 3.5 V, V5 = 14 V, V7 = 0.5 V. I2 is the CO pin sink current (I_{COL}) at that time.

5. 2. 2 Active "L"

(1) CO pin leakage current (IcolL)

Set SW5 to ON after setting V1 to V4 = 3.5 V, V5 = 14 V, V7 = 28 V. I2 is the CO pin leakage current (I_{COLL}) at that time.

(2) CO pin sink current (I_{COL})

Set SW5 to ON after setting V1 to V4 = 3.5 V, V5 = 0 V, V7 = 0.5 V. I2 is the CO pin sink current (I_{COL}) at that time.

5. 3 S-8224B Series

Set SW4 and SW5 to OFF.

5. 3. 1 CO pin source current (Ісон)

Set SW5 to ON after setting V1 to V4 = 3.5 V, V5 = 0 V, V7 = $V_{COH} - 0.5$ V. I2 is the CO pin source current (I_{COH}) at that time.

5. 3. 2 CO pin sink current (I_{COL})

Set SW5 to ON after setting V1 to V4 = 3.5 V, V5 = 14 V, V7 = 0.5 V. I2 is the CO pin sink current (I_{COL}) at that time.

6. Overcharge detection delay time (t_{CU}), overcharge release delay time (t_{CL}) (Test circuit 1)

Set SW1 to OFF in CMOS output product of the S-8224A Series and in the S-8224B Series, and set SW1 to ON in Nch open-drain output product of the S-8224A Series.

Increase V1 up to 5.2 V after setting V0 = 0 V, V1 = V2 = V3 = V4 = 3.5 V. The overcharge detection delay time (t_{CL}) is the time period until the CO pin output inverts. After that, decrease V1 down to 3.5 V. The overcharge release delay time (t_{CL}) is the time period until the CO pin output inverts.

7. CTL pin response delay time (t_{CTL}) (Test circuit 2)

Set SW1 to OFF in CMOS output product of the S-8224A Series and in the S-8224B Series, and set SW1 to ON in Nch open-drain output product of the S-8224A Series.

Decrease V5 down to 0 V after setting V1 = V2 = V3 = V4 = 3.5 V, V5 = 14 V. The CTL pin response delay time (t_{CTL}) is the time period until the CO pin output inverts.

8. Overcharge timer reset delay time (t_{TR}) (Test circuit 1)

Set SW1 to OFF in CMOS output product of the S-8224A Series and in the S-8224B Series, and set SW1 to ON in Nch open-drain output product of the S-8224A Series.

Increase V1 up to 5.2 V (first rise), and decrease V1 down to 3.5 V within the overcharge detection delay time (t_{CU}) after setting V0 = 0 V, V1 = V2 = V3 = V4 = 3.5 V. After that, increase V1 up to 5.2 V again (second rise), and detect the time period until the CO pin output inverts.

When the period from when V1 has fallen to the second rise is short, CO pin output inverts after t_{CU} has elapsed since the first rise. If the period is gradually made longer, CO pin output inverts after t_{CU} has elapsed since the second rise. The overcharge timer reset delay time (t_{TR}) is the period from V1 fall until the second rise at that time.

9. Transition time to test mode (t_{TST}) (Test circuit 1)

Set SW1 to OFF in CMOS output product of the S-8224A Series and in the S-8224B Series, and set SW1 to ON in Nch open-drain output product of the S-8224A Series.

Increase V0 up to 8.5 V, and decrease V0 again to 0 V after setting V0 = 0 V, V1 = V2 = V3 = V4 = 3.5 V.

When the period from when V0 was raised to when it has fallen is short, if an overcharge detection operation is performed subsequently, the delay time is t_{CU} . However, when the period from when V0 is raised to when it has fallen is gradually made longer, the delay time during the subsequent overcharge detection operation is shorter than t_{CU} . The transition time to test mode (t_{TST}) is the period from when V0 was raised to when it has fallen at that time.

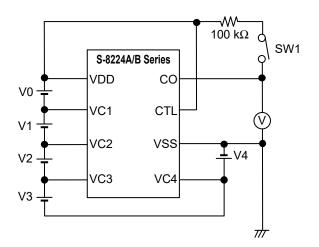


Figure 5 Test Circuit 1

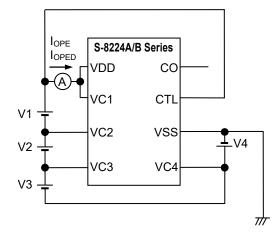


Figure 7 Test Circuit 3

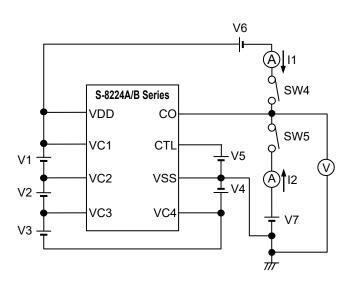


Figure 9 Test Circuit 5

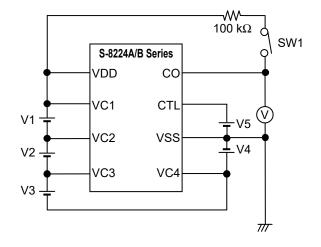


Figure 6 Test Circuit 2

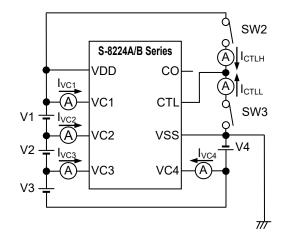


Figure 8 Test Circuit 4

Operation

Remark Refer to "**Battery Protection IC Connection Examples**".

1. Normal status

If the voltage of each of the batteries is lower than "the overcharge detection voltage (V_{CU}) + the overcharge hysteresis voltage (V_{HC})", the CO pin output changes to "L" (active "H") or "H" (active "L"). This is called normal status.

2. Overcharge status

When the voltage of one of the batteries exceeds V_{CU} during charging under normal conditions and the status is retained for the overcharge detection delay time (t_{CU}) or longer, CO pin output inverts. This status is called overcharge status. Connecting FET to the CO pin provides charge control and a second protection.

If the voltage of each of the batteries is lower than $V_{CU} + V_{HC}$ and the status is retained for the overcharge release delay time (t_{CL}) or longer, S-8224A/B Series changes to normal status.

3. Overcharge timer reset function

When an overcharge release noise that forces the voltage of one of the batteries temporarily below V_{CU} is input during t_{CU} from when V_{CU} is exceeded to when charging is stopped, t_{CU} is continuously counted if the time the overcharge release noise persists is shorter than the overcharge timer reset delay time (t_{TR}). Under the same conditions, if the time the overcharge release noise persists is t_{TR} or longer, counting of t_{CU} is reset once. After that, when V_{CU} has been exceeded, counting t_{CU} resumes.

4. CTL pin

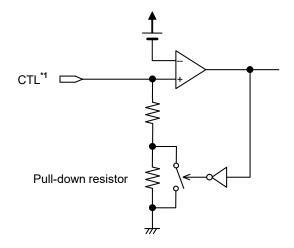
The S-8224A/B Series has control pins.

In the S-8224A/B Series, the CTL pin is used to control the output voltage of the CO pin. The CTL pin takes precedence over the overcharge detection circuit.

CTL Pin CO Pin					
"H"	Normal status ^{*1}				
Open	Detection status				
"L"	Detection status				

Table 8 Status Set by CTL Pin

*1. The status is controlled by the overcharge detection circuit.



*1. In the S-8224A/B Series, the inversion voltage "H" to "L" or "L" to "H" of the CTL pin is the VDD pin voltage – 2.8 V typ., and does not have the hysteresis.

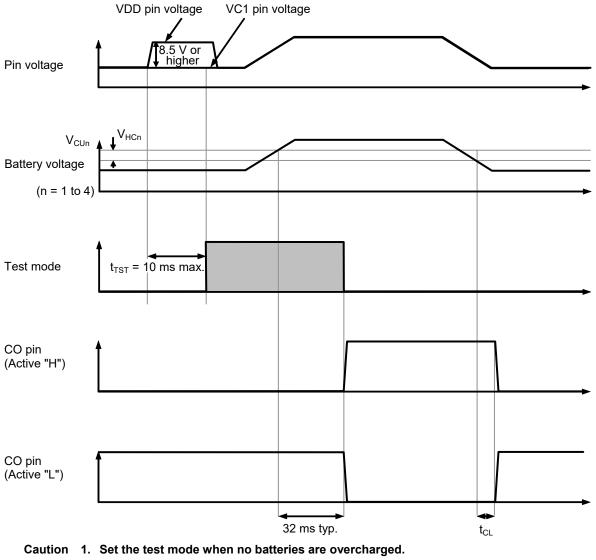
Figure 10 Internal Equivalent Circuit of CTL Pin

Caution In the S-8224A/B Series, since the CTL pin implements high resistance of 7 M Ω to 24 M Ω for pull down, be careful of external noise application. If an external noise is applied, the CO pin may become "H". Perform thorough evaluation using the actual application.

5. Test mode

In the S-8224A/B Series, the overcharge detection delay time (t_{CU}) can be shortened by entering the test mode. The test mode can be set by retaining the VDD pin voltage 8.5 V or more higher than the VC1 pin voltage for at least 10 ms (V1 = V2 = V3 = V4 = 3.5 V, Ta = +25 °C). The status is retained by the internal latch and the test mode is retained even if the VDD pin voltage is decreased to the same voltage as that of the VC1 pin.

If the CO pin becomes detection status when the delay time has elapsed after overcharge detection, the latch for retaining the test mode is reset and the S-8224A/B Series exits from the test mode.



2. The overcharge timer reset delay time (t_{TR}) is not shortened in the test mode.

Figure 11

■ Timing Charts

1. Overcharge detection operation (With overcharge timer reset function)

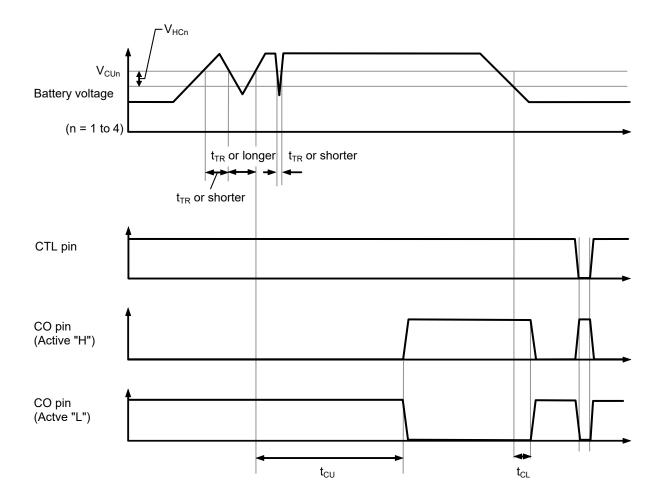
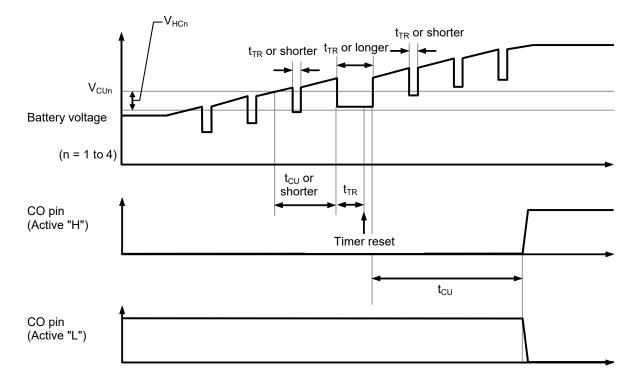


Figure 12

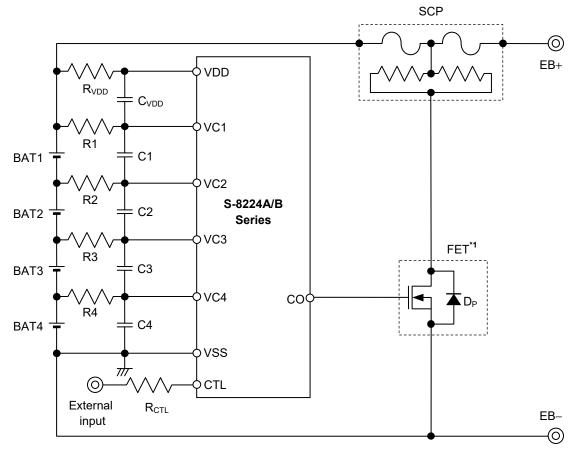


2. Overcharge timer reset operation (With overcharge timer reset function)



Battery Protection IC Connection Examples

1. 4-serial cell



***1.** The S-8224B Series limits its CO pin output voltage to 11.5 V max., so a FET with the gate withstand voltage of 12 V can be used.

Fig	ure	14
· · · •		

Table 9 0	Constants for	External Com	ponents
-----------	---------------	---------------------	---------

No.	Part	Min.	Тур.	Max.	Unit
1	R1 to R4	0.3	1	10	kΩ
2	C1 to C4, C _{VDD}	0.01	0.1	1	μF
3	Rvdd	300	330	1000	Ω

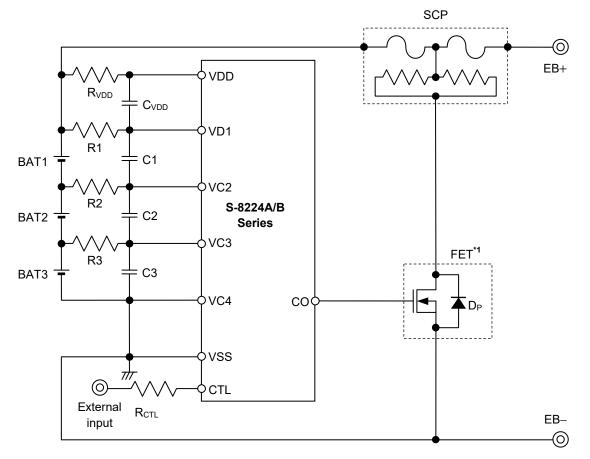
Caution 1. The above constants are subject to change without prior notice.

2. It has not been confirmed whether the operation is normal or not in circuits other than the above example of connection. In addition, the example of connection shown above and the constant will not guarantee successful operation. Perform thorough evaluation using the actual application to set the constant.

- 3. Set the same constants to R1 to R4 and to C1 to C4 and $C_{\text{VDD}}.$
- 4. Since the CO pin may become the detection status transiently when the battery is being connected, be sure to connect the positive terminal of BAT1 last in order to prevent the terminal protection fuse from cutoff.

BATTERY PROTECTION IC FOR 2-SERIAL TO 4-SERIAL CELL PACK (SECONDARY PROTECTION) S-8224A/B Series Rev.1.4_00

2. 3-serial cell



*1. The S-8224B Series limits its CO pin output voltage to 11.5 V max., so a FET with the gate withstand voltage of 12 V can be used.

Figure 15

No.	Part	Min.	Тур.	Max.	Unit
1	R1 to R3	0.3	1	10	kΩ
2	C1 to C3, C _{VDD}	0.01	0.1	1	μF
3	R _{VDD}	300	330	1000	Ω

Caution 1. The above constants are subject to change without prior notice.

- 2. It has not been confirmed whether the operation is normal or not in circuits other than the above example of connection. In addition, the example of connection shown above and the constant will not guarantee successful operation. Perform thorough evaluation using the actual application to set the constant.
- 3. Set the same constants to R1 to R3 and to C1 to C3 and $C_{\text{VDD}}.$
- 4. Since the CO pin may become the detection status transiently when the battery is being connected, connect the positive terminal of BAT1 last in order to prevent the protection fuse from cutoff.

3. 2-serial cell

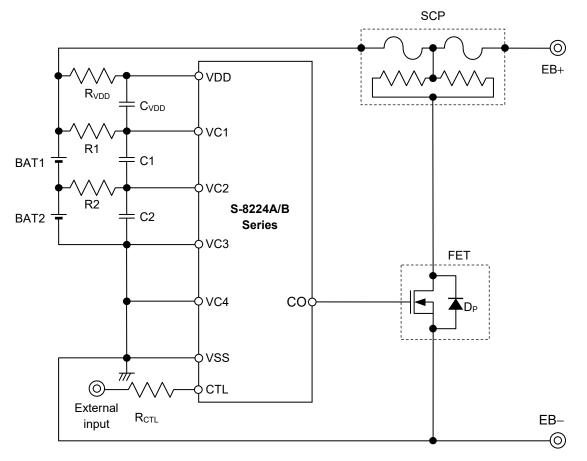


Figure 16

Table 11 Constants for External Components
--

No.	Part	Min.	Тур.	Max.	Unit
1	R1 to R2	0.3	1	10	kΩ
2	C1 to C2, C _{VDD}	0.01	0.1	1	μF
3	Rvdd	300	330	1000	Ω

Caution 1. The above constants are subject to change without prior notice.

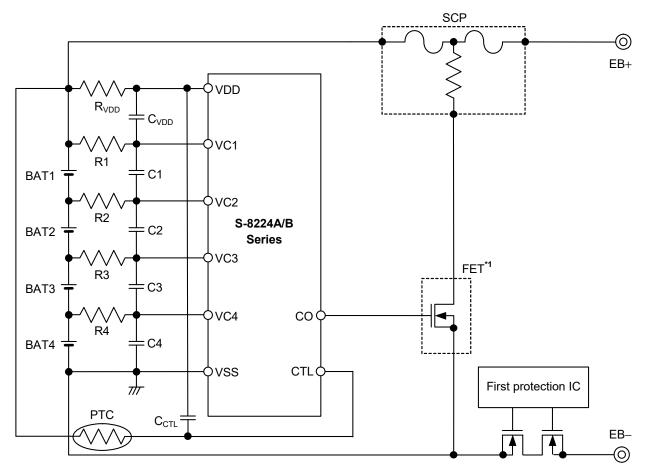
- 2. It has not been confirmed whether the operation is normal or not in circuits other than the above example of connection. In addition, the example of connection shown above and the constant will not guarantee successful operation. Perform thorough evaluation using the actual application to set the constant.
- 3. Set the same constants to R1 to R2, and to C1 to C2 and C_{VDD} .
- 4. Since the CO pin may become the detection status transiently when the battery is being connected, connect the positive terminal of BAT1 last in order to prevent the protection fuse from cutoff.

Precaution

- Do not connect batteries charged with $V_{CU} + V_{HC}$ or higher.
- If the connected batteries include a battery charged with V_{CU} + V_{HC} or higher, the S-8224A/B series may become the overcharge status after all pins are connected.
- In some application circuits, even if an overcharged battery is not included, the order of connecting batteries may be restricted to prevent transient output of the CO pin detection pulses when the batteries are connected. Perform thorough evaluation with the actual application circuit.
- Before the battery connection, short-circuit the battery side pins R_{VDD} and R1, shown in the figures in "■ Battery Protection IC Connection Examples".
- The application conditions for the input voltage, output voltage, and load current should not exceed the power dissipation.
- Do not apply to this IC an electrostatic discharge that exceeds the performance ratings of the built-in electrostatic protection circuit.
- ABLIC Inc. claims no responsibility for any disputes arising out of or in connection with any infringement of patents owned by a third party by products including this IC.

Example of Application Circuit

1. Overheat protection via PTC



*1. The S-8224B Series limits its CO pin output voltage to 11.5 V max., so a FET with the gate withstand voltage of 12 V can be used.

Figure 17

- Caution 1. The above connection example will not guarantee successful operation. Perform thorough evaluation using the actual application.
 - 2. A pull-down resistor is included in the CTL pin. To perform overheat protection via the PTC in the S-8224A/B Series, connect the PTC before connecting batteries.
 - 3. When the power fluctuation is large, connect the power supply of the PTC to the VDD pin of the S-8224A/B Series.
 - 4. Since the CO pin may become the detection status transiently when the battery is being connected, connect the positive terminal of BAT1 last in order to prevent the three terminal protection fuse from cutoff.

[For SCP, contact]

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[For PTC, contact]

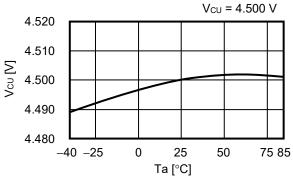
Murata Manufacturing Co., Ltd. Thermistor Products Department Nagaokakyo-shi, Kyoto, 617-8555, Japan TEL +81-75-955-6863 Contact Us: http://www.murata.com/contact/index.html

ABLIC Inc.

Characteristics (Typical Data)

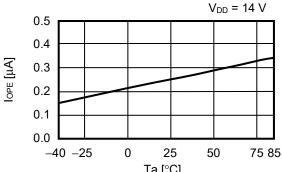
1. Detection voltage

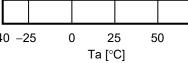




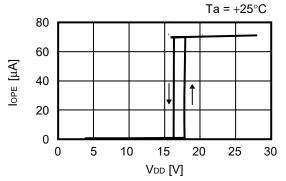
2. Current consumption





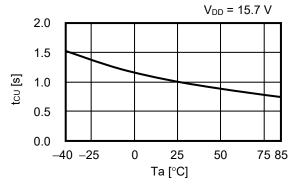


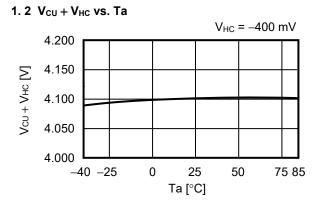
2. 3 IOPE VS. VDD



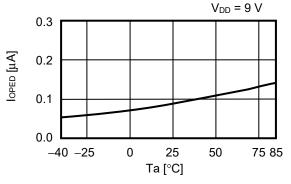
3. Delay time



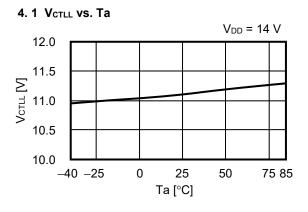




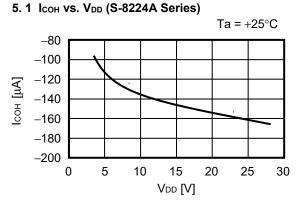




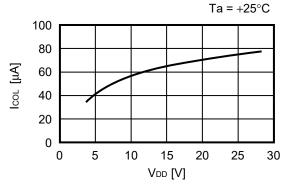
4. CTL pin



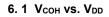
5. Output current

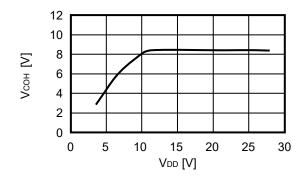


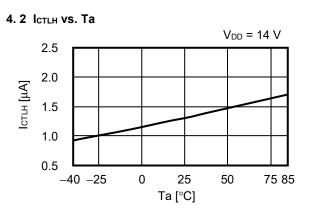




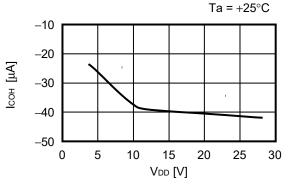
6. Output voltage





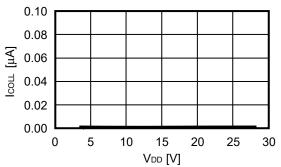


5. 2 ICOH VS. VDD (S-8224B Series)



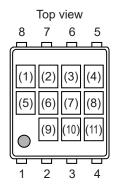






Marking Specifications

1. SNT-8A



(1) (2) to (4) (5), (6)

Blank (7) to (11) Lot number

Blank

Product name vs. Product code

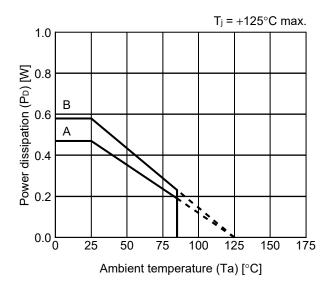
Product name	Product code		
Product name	(2)	(3)	(4)
S-8224AAS-I8T1U	5	R	S
S-8224AAT-I8T1U	5	R	Т
S-8224AAU-I8T1U	5	R	U
S-8224AAV-I8T1U	5	R	V
S-8224AAW-I8T1U	5	R	W
S-8224AAX-I8T1U	5	R	Y
S-8224ABA-I8T1U	6	Z	А
S-8224ABB-I8T1U	6	Z	В
S-8224ABC-I8T1U	6	Z	С
S-8224ABD-I8T1U	6	Z	D
S-8224ABE-I8T1U	6	Z	E
S-8224ABF-I8T1U	6	Z	F

Product name	Product code		
Product name	(2)	(3)	(4)
S-8224BAA-I8T1U	5	S	А
S-8224BAB-I8T1U	5	S	В
S-8224BAC-I8T1U	5	S	С

Product code (Refer to Product name vs. Product code)

Power Dissipation

SNT-8A

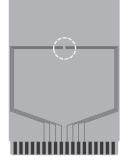


Board	Power Dissipation (P _D)	
Α	0.47 W	
В	0.58 W	
С	_	
D	_	
E	_	

SNT-8A Test Board

(1) Board A

O IC Mount Area



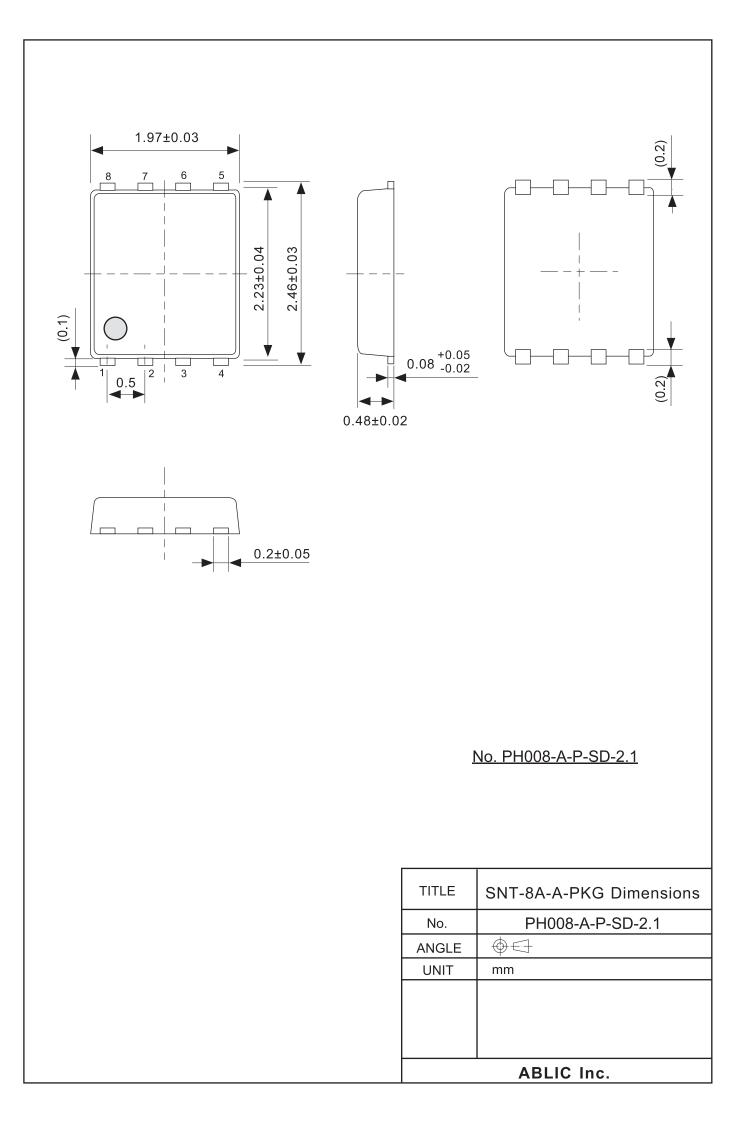
Item		Specification		
Size [mm]		114.3 x 76.2 x t1.6		
Material		FR-4		
Number of copper foil layer		2		
Copper foil layer [mm]	1	Land pattern and wiring for testing: t0.070		
	2	-		
	3	-		
	4	74.2 x 74.2 x t0.070		
Thermal via		-		

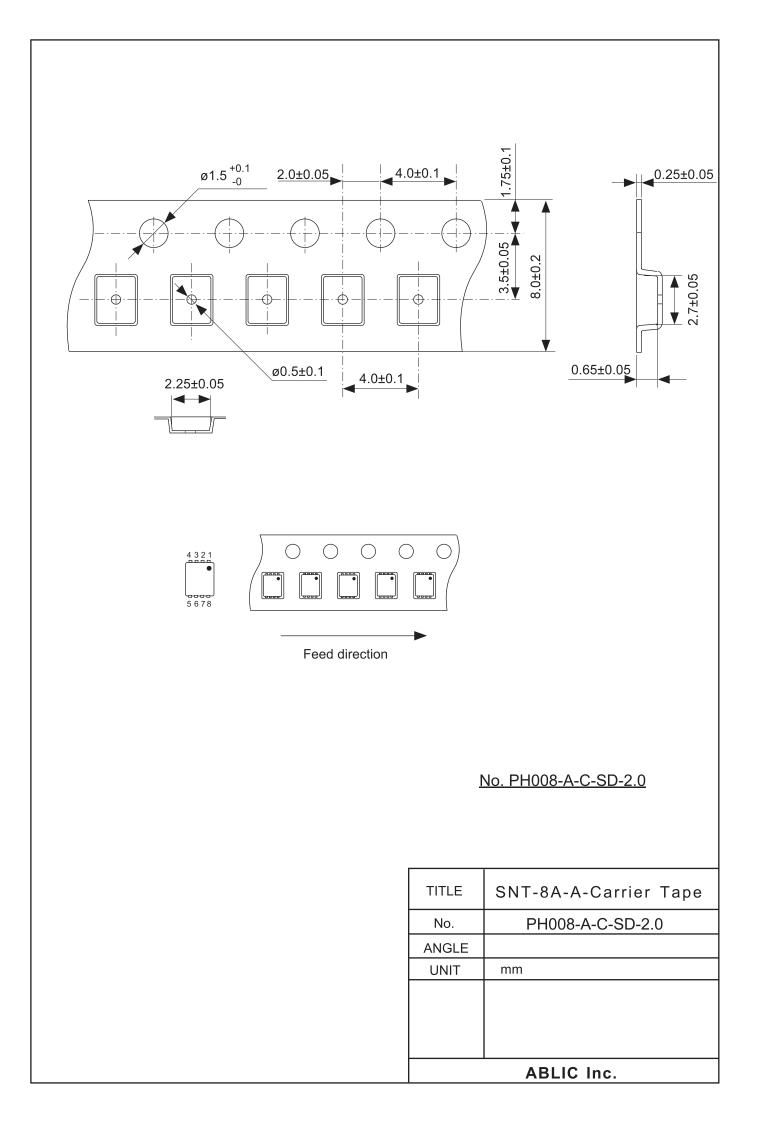
(2) Board B

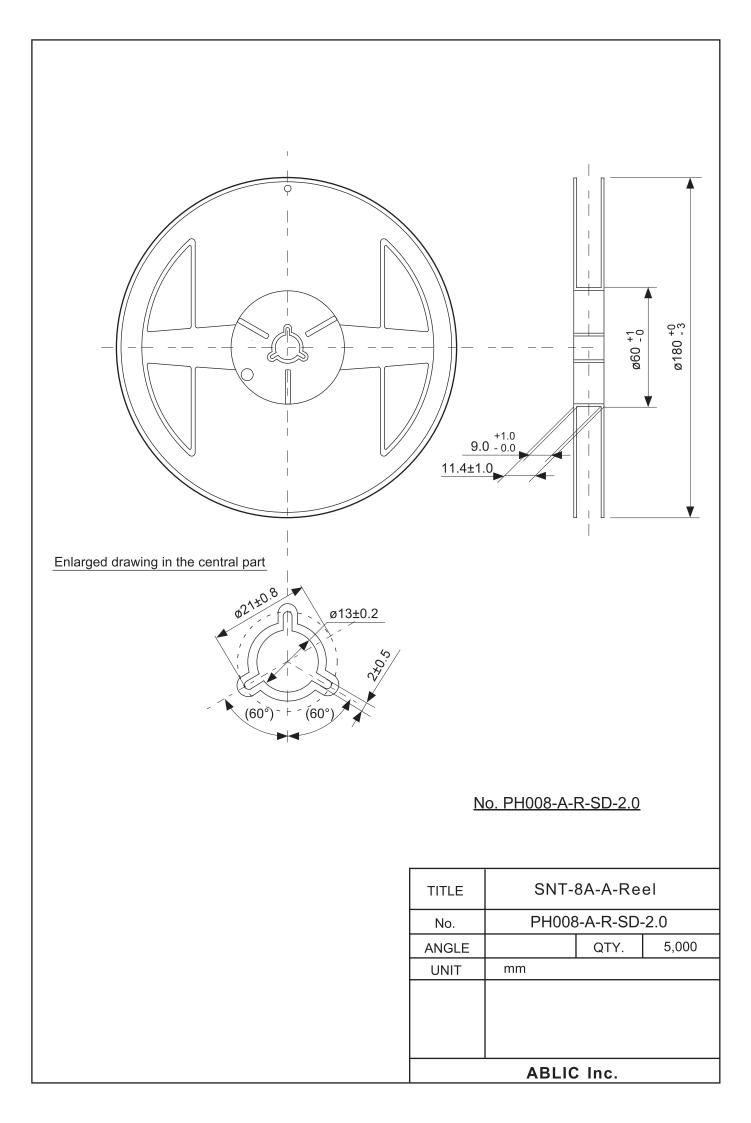


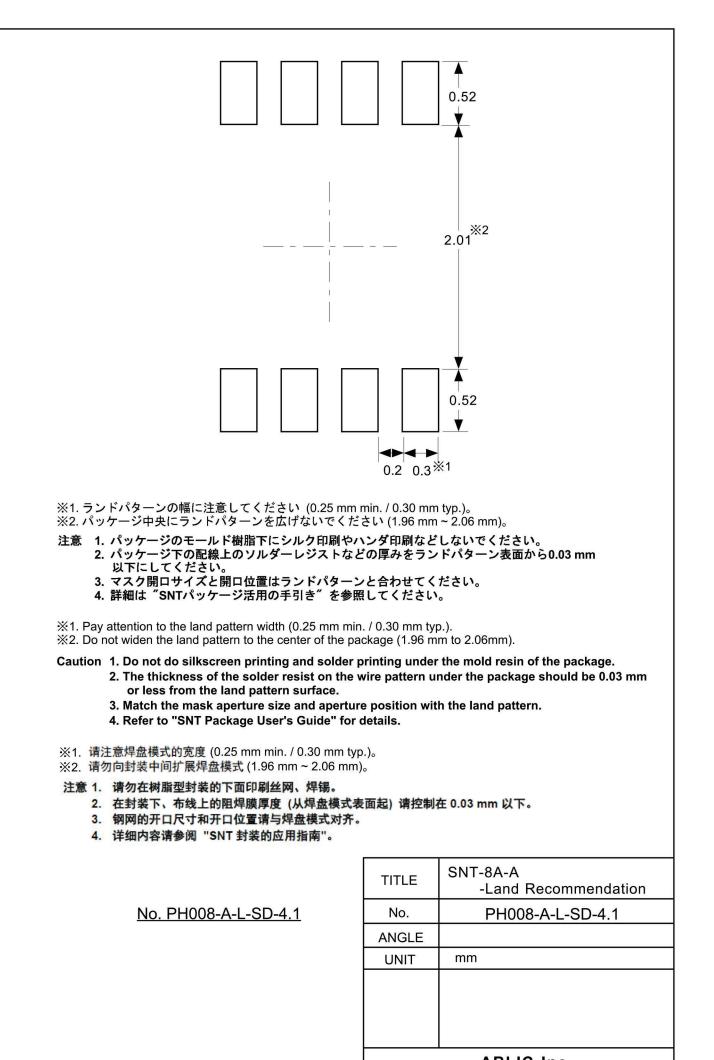
Item		Specification		
Size [mm]		114.3 x 76.2 x t1.6		
Material		FR-4		
Number of copper foil layer		4		
Copper foil layer [mm]	1	Land pattern and wiring for testing: t0.070		
	2	74.2 x 74.2 x t0.035		
	3	74.2 x 74.2 x t0.035		
	4	74.2 x 74.2 x t0.070		
Thermal via		-		

No. SNT8A-A-Board-SD-1.0









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